CMOS Digital Integrated Circuits Silicon Monolithic

TC7SB3157CFU

1. Functional Description

• Single 1-of-2 Multiplexer/Demultiplexer

2. General

The TC7SB3157CFU is a high-speed CMOS single 1-of-2 multiplexer/demultiplexer. The low ON resistance of the switch allows connections to be made with minimal propagation delay time.

This device is 1 to 2 multiplexer/demultiplexer controlled by the select input (S). The A input is connected to B1 or B2 output based on the selection of Control input (S).

All inputs are equipped with protection circuits against static discharge.

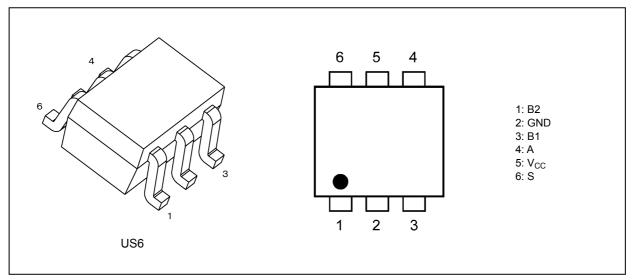
3. Features

- (1) AEC-Q100 (rev.H) Grade 1 qualified (Note 1)
- (2) Wide operating temperature range: $T_{opr} = -40$ to 125 °C (Note 2)
- (3) Operating voltage: V_{CC} = 1.65 to 5.5 V
- (4) ON capacitance: $C_{I/O} = 15 \text{ pF}$ Switch On (typ.) $@V_{CC} = 5.0 \text{ V}$
- (5) ON resistance: $R_{ON} = 4 \Omega$ (typ.) $@V_{CC} = 4.5 V$, $V_{IS} = 0 V$
- (6) Package: US6

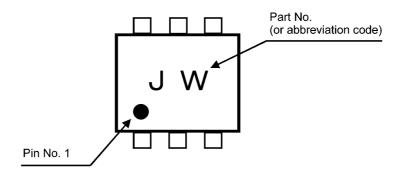
Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

Note 2: For devices with the ordering part number ending in (CT. T_{opr} = -40 to 85 °C for the other devices.

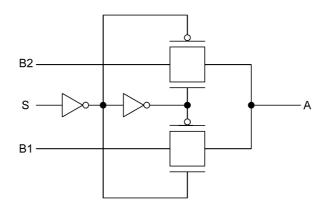
4. Packaging and Pin Assignment



5. Marking



6. Block Diagram



7. Principle of Operation

7.1. Truth Table

Inputs S	Function
L	A port = B1 port
Н	A port = B2 port

8. Absolute Maximum Ratings (Note) (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 7.0	V
Input voltage (S)	V _{IN}		-0.5 to 7.0	1
Switch I/O voltage	Vs		-0.5 to V _{CC} +0.5]
Clamp diode current	l _{IK}		-50	mA
Switch I/O current	I _S		50]
Power dissipation	PD		200	mW
V _{CC} /ground current	I _{CC} /I _{GND}		±100	mA
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

9. Operating Ranges (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		1.65 to 5.5	V
Input voltage (S)	V _{IN}		0 to 5.5	
Switch I/O voltage	Vs		0 to V _{CC}	
Operating temperature	T _{opr}	(Note 1)	-40 to 125	°C
		(Note 2)	-40 to 85	
Input rise time	dt/dv		0 to 10	ns/V
Input fall time	dt/dv		0 to 10	

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs and bus inputs must be tied to either V_{CC} or GND.

Note 1: For devices with the ordering part number ending in (CT.

Note 2: For devices except those with the ordering part number ending in (CT.

10. Electrical Characteristics

10.1. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Min	Тур.	Max	Unit
High-level input voltage	V _{IH}		—	1.65 to 1.95	$0.8 \times V_{CC}$	_	—	V
				2.3 to 5.5	$0.7\times V_{CC}$	_	_	
Low-level input voltage	VIL		—	1.65 to 1.95	—	_	$0.2 \times V_{CC}$	V
				2.3 to 5.5	_		$0.3 \times V_{CC}$	
Input leakage current	I _{IN}		V _{IN} = 0 to 5.5 V	1.65 to 5.5	_		±1.0	μA
Switch OFF-state leakage current	I _{SZ}		B1, B2 = 0 to V _{CC}	1.65 to 5.5	_	_	±10	μA
ON-resistance	R _{ON}		V _{IS} = 0 V, I _{IS} = 30 mA	4.5	—	4	7	Ω
		(Note 2)	V _{IS} = 2.4 V, I _{IS} = 30 mA	4.5	_	5	12	
			V _{IS} = 4.5 V, I _{IS} = 30 mA	4.5	_	6	10	
			V _{IS} = 0 V, I _{IS} = 24 mA	3.0	_	5	9	
			V _{IS} = 3.0 V, I _{IS} = 24 mA	3.0	_	7	14	
			V _{IS} = 0 V, I _{IS} = 8 mA	2.3	—	6	12	
			V _{IS} = 2.3 V, I _{IS} = 8 mA	2.3	_	9	18	
			V _{IS} = 0 V, I _{IS} = 4 mA	1.65	_	8	20	
			V _{IS} = 1.65 V, I _{IS} = 4 mA	1.65	—	15	30	
Quiescent supply	I _{CC}		$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$ A	5.5	_		10	μA
current	ΔI_{CC}		V _{IN} = V _{CC} - 0.6 V	5.5	_	_	50	

Note 1: All typical values are at T_a = 25 °C.

Note 2: Measured by the voltage drop between A and B pins at the indicated current through the switch. On-resistance is determined by the lower of the voltages on the two (A or B) pins.

10.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C)

Characteristics	Symbol	Note	Test Condition	V_{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}		_	1.65 to 1.95	0.8×V _{CC}	_	V
				2.3 to 5.5	0.7×V _{CC}	_	
Low-level input voltage	V _{IL}		_	1.65 to 1.95	_	0.2×V _{CC}	V
				2.3 to 5.5	_	0.3×V _{CC}	
Input leakage current	I _{IN}		V _{IN} = 0 to 5.5 V	1.65 to 5.5	_	±2.0	μA
Switch OFF-state leakage current	I _{SZ}		B1, B2 = 0 to V _{CC}	1.65 to 5.5	—	±20	
ON-resistance	R _{ON}	(Note 1)	V _{IS} = 0 V, I _{IS} = 30 mA	4.5	_	9	Ω
			V _{IS} = 2.4 V, I _{IS} = 30 mA	4.5	_	14	
			V _{IS} = 4.5 V, I _{IS} = 30 mA	4.5	_	12	
			V _{IS} = 0 V, I _{IS} = 24 mA	3.0	—	11	
			V _{IS} = 3.0 V, I _{IS} = 24 mA	3.0	_	16	
			V _{IS} = 0 V, I _{IS} = 8 mA	2.3	_	15	
			V _{IS} = 2.3 V, I _{IS} = 8 mA	2.3	_	21	
			_{IS} = 0 V, I _{IS} = 4 mA	1.65	_	23	
			V _{IS} = 1.65 V, I _{IS} = 4 mA	1.65	_	33	
Quiescent supply	I _{CC}		$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$ A	5.5	_	100	μA
current	Δl _{CC}		V _{IN} = V _{CC} - 0.6 V	5.5	_	100	

Note 1: Measured by the voltage drop between A and B pins at the indicated current through the switch. On-resistance is determined by the lower of the voltages on the two (A or B) pins.

10.3. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Min	Max	Unit
3-state output enable time	t _{PZL} /		See Fig. 10.2.1, 10.2.2,	5.0 ± 0.5	_	4	ns
	t _{PZH}		Table 10.2.1.	$\textbf{3.3}\pm\textbf{0.3}$	_	6	
				$\textbf{2.5}\pm\textbf{0.2}$	_	8	
				1.8 ± 0.15		16	
3-state output disable time	t _{PLZ} /		See Fig. 10.2.1, 10.2.2,	5.0 ± 0.5	_	4.5	ns
	t _{PHZ}		Table 10.2.1.	$\textbf{3.3}\pm\textbf{0.3}$	_	7	
				$\textbf{2.5}\pm\textbf{0.2}$	_	9	
				1.8 ± 0.15	_	16	

10.4. AC Characteristics (Unless otherwise specified, T_a = -40 to 125 ℃)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Min	Max	Unit
3-state output enable time	t _{PZL} /		See Fig. 10.2.1, 10.2.2,	5.0 ± 0.5	_	6	ns
	t _{PZH}		Table 10.2.1.	$\textbf{3.3}\pm\textbf{0.3}$	_	8	
				2.5 ± 0.2	_	10	
				1.8 ± 0.15	_	18	
3-state output disable time	t _{PLZ} /		See Fig. 10.2.1, 10.2.2,	5.0 ± 0.5	_	6.5	ns
	t _{PHZ}		Table 10.2.1.	3.3 ± 0.3	_	9	
				2.5 ± 0.2	_	11	
				1.8 ± 0.15		18	

10.5. Capacitive Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Note	Test Condition	V_{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	(Note 1)	V _{IN} = 0 V	5.0	4	pF
Switch terminal OFF-capacitance (B port)	C _{I/O}		V _{I/O} = 0 V	5.0	5	
Switch terminal ON-capacitance (A port)				5.0	15	
Switch terminal ON-capacitance (B port)				5.0	15	

Note 1: Parameter guaranteed by design.

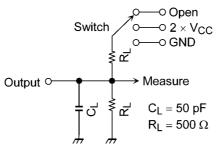


Fig. 10.2.1 AC Test Circuit

Table 10.2.1 Parameter for AC Test Circuit

Parameter	Switch	
t _{PLZ} , t _{PZL}	$2 \times V_{CC}$	
t _{PHZ} , t _{PZH}	GND	

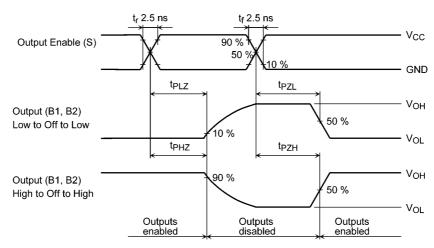


Fig. 10.2.2 AC Waveform tPLZ, tPHZ, tPZL, tPZH

11. Rise and Fall Time (tr/tf)

The $t_{r(out)}$ and $t_{f(out)}$ values of the output signals are affected by the CR time constant of the input, which consists of the switch terminal capacitance ($C_{I/O}$) and the on-resistance (R_{ON}) of the input.

In practice, the $t_{r(out)}$ and $t_{f(out)}$ values are also affected by the circuit's capacitance and resistance components other than the capacitance of TC7SB3157CFU

The $t_{r}\!/t_{f(out)}$ values can be approximated as follows.

(Figure 11.1, Table 11.1 shows the test circuit.)

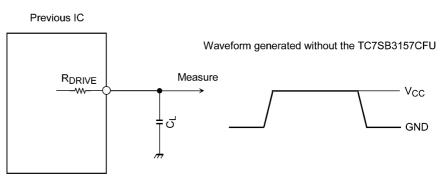
$$\label{eq:tr} \begin{split} t_r / t_{f(out)} \ (approx) = & \ (C_{I/O} + C_L) \ \cdot \ (R_{DRIVE} + R_{ON}) \ \cdot \ ln \ (((V_{OH} \cdot V_{OL}) \cdot V_M) \ / \ (V_{OH} \cdot V_{OL})) \end{split}$$
 Where, R_{DRIVE} is the output impedance of the previous-stage circuit.

Calculation example:

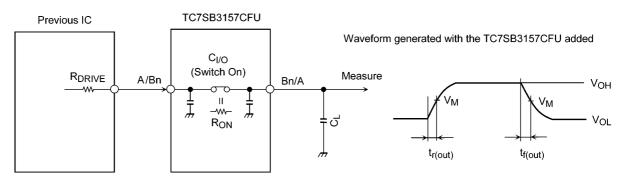
 $t_{r(out)} \ (\text{approx}) = - \ (15 + 15) \ E - 12 \ \cdot \ (120 + 4) \ \cdot \ \ln \ (((4.5 - 0) - 2.25) \ / \ (4.5 - 0)) \approx 2.6 \ \text{ns}$

Calculation conditions:

 V_{CC} = 4.5 V, C_L = 15 pF, R_{DRIVE} = 120 Ω (output impedance of the previous IC), V_M = 2.25 V (V_{CC} /2) Output of the previous IC = digital (i.e., high-level voltage = V_{CC} , low-level voltage = GND)



 R_{DRIVE} = output impedance of the previous IC



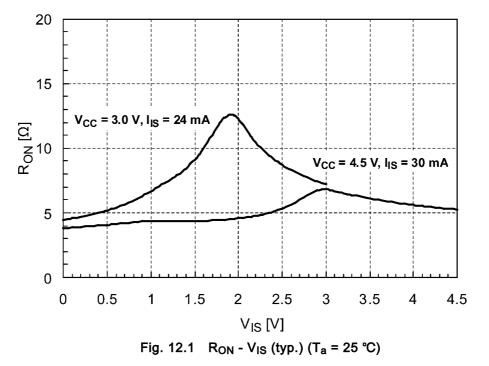
 R_{DRIVE} = output impedance of the previous IC

Fig. 11.1 Calculation Circuit

Table 11.1	Calculation	Circuit

Characteristics	V_{CC} = 5.0 \pm 0.5 V
V _M	V _{CC} /2

12. Characteristics Curves (Note)

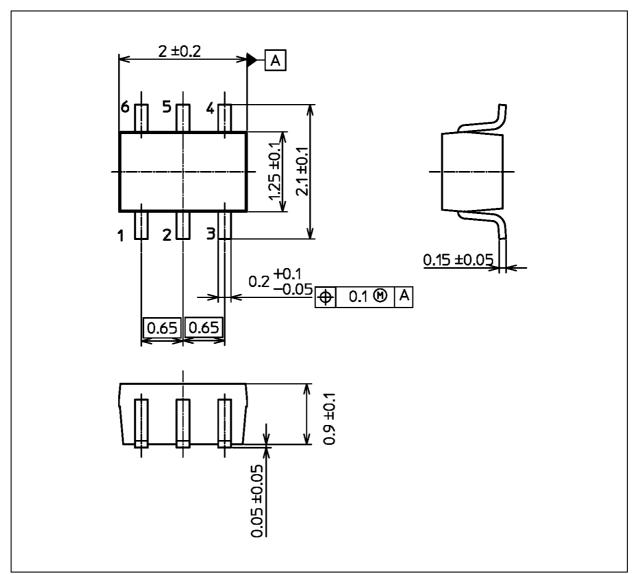


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



Package Dimensions

Unit: mm



Weight: 0.007 g (typ.)

	Package Name(s)
JEDEC: SOT-363	
Nickname: US6	

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